

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



# Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China









# **Radar Pulsed Power Transistor** 5W, 3.1-3.5 GHz, 2µs Pulse, 10% Duty

## **M/A-COM Products** Released, 10 Aug 07

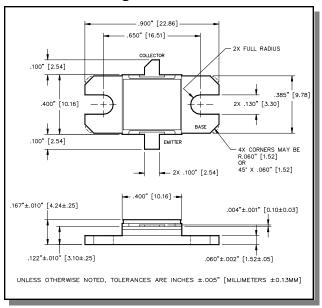
#### **Features**

- NPN silicon microwave power transistors
- Common base configuration
- Broadband Class C operation
- High efficiency inter-digitized geometry
- Diffused emitter ballasting resistors
- Gold metallization system
- Internal input and output impedance matching
- Hermetic metal/ceramic package
- RoHS compliant

#### **Absolute Maximum Ratings at 25°C**

Parameter	Symbol	Rating	Units
Collector-Emitter Voltage	$V_{CES}$	60	V
Emitter-Base Voltage	$V_{EBO}$	3.0	V
Collector Current (Peak)	Ic	0.75	Α
Power Dissipation @ +25°C	P <sub>TOT</sub>	60	W
Storage Temperature	T <sub>STG</sub>	-65 to +200	°C
Junction Temperature	$T_J$	200	°C

#### **Outline Drawing**



#### Electrical Specifications: T<sub>C</sub> = 25 ± 5°C (Room Ambient)

Parameter	Test Conditions	Frequency	Symbol	Min	Max	Units
Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 10mA		BV <sub>CES</sub>	60	-	V
Collector-Emitter Leakage Current	V <sub>CE</sub> = 40V		I <sub>CES</sub>	-	1.0	mA
Thermal Resistance	Vcc = 33V, Pin = 0.7W	F = 3.1, 3.3, 3.5 GHz	R <sub>TH(JC)</sub>	1	3.5	°C/W
Output Power	Vcc = 33V, Pin = 0.7W	F = 3.1, 3.3, 3.5 GHz	P <sub>OUT</sub>	5.0	-	W
Power Gain	Vcc = 33V, Pin = 0.7W	F = 3.1, 3.3, 3.5 GHz	G <sub>P</sub>	8.5	=	dB
Collector Efficiency	Vcc = 33V, Pin = 0.7W	F = 3.1, 3.3, 3.5 GHz	ης	30	-	%
Input Return Loss	Vcc = 33V, Pin = 0.7W	F = 3.1, 3.3, 3.5 GHz	RL	-	-6	dB
Load Mismatch Tolerance	Vcc = 33V, Pin = 0.7W	F = 3.1, 3.3, 3.5 GHz	VSWR-T	-	2:1	-

<sup>•</sup> North America Tel: 800.366.2266 / Fax: 978.366.2266 Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298 Visit www.macomtech.com for additional data sheets and product information.

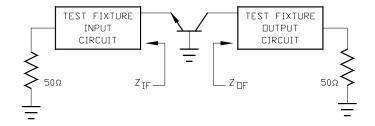


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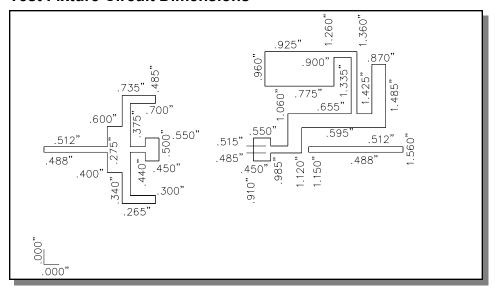
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#### **RF Test Fixture Impedance**

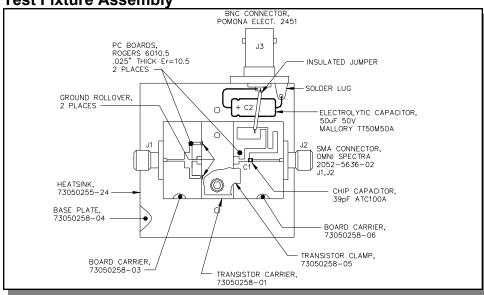
F (GHz)	Z <sub>IF</sub> (Ω)	Z <sub>OF</sub> (Ω)
3.1	24 - j4.4	24 - j20
3.3	20 - j0.7	18 - j11
3.5	17 + j3.9	15 - j3.0



#### **Test Fixture Circuit Dimensions**



**Test Fixture Assembly** 



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PRELIMINARY: Data Sheets contain information regarding a product M/A-COM Technology Solutions has under development. Performance is based on engineering tests. Specifications are typical. Mechanical outline has been fixed. Engineering samples and/or test data may be available. Commitment to produce in volume is not guaranteed.

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